SCES471 - AUGUST 2003

- Optimized for 1.8-V Operation and Is 3.6-V
 I/O Tolerant to Support Mixed-Mode Signal Operation
- I_{off} Supports Partial-Power-Down Mode Operation
- Sub 1-V Operable
- Max t_{pd} of 2.2 ns at 1.8-V
- Low Power Consumption, 10-μA Max I_{CC}
- ±8-mA Output Drive at 1.8 V
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

RGY PACKAGE (TOP VIEW) 14 2 13 6A 2A 3 6Y 12 2Y 4 11 5A ЗА 5 10 5Y 3Y 6 9 4A 8

description/ordering information

This hex inverter buffer/driver is operational at 0.8-V to 2.7-V V_{CC} , but is designed specifically for 1.65-V to 1.95-V V_{CC} operation.

The outputs of the SN74AUC06 are open drain and can be connected to other open-drain outputs to implement active-low wired-OR or active-high wired-AND functions.

This device is fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

ORDERING INFORMATION

TA	PACKAGE	†	ORDERABLE PART NUMBER	TOP-SIDE MARKING
-40°C to 85°C	QFN – RGY	Tape and reel	SN74AUC06RGYR	MS06

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

FUNCTION TABLE (each inverter)

IN	IPUT A	OUTPUT Y
	Н	L
	L	Н

logic diagram, each buffer/driver (positive logic)



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



SN74AUC06 HEX INVERTER BUFFER/DRIVER WITH OPEN-DRAIN OUTPUTS

SCES471 – AUGUST 2003

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}	–0.5 V to 3.6 V
Input voltage range, V _I (see Note 1)	0.5 V to 3.6 V
Output voltage range, V _O (see Note 1)	\dots –0.5 V to 3.6 V
Input clamp current, I _{IK} (V _I < 0)	–50 mA
Output clamp current, I _{OK} (V _O < 0)	–50 mA
Continuous output current, I _O	±20 mA
Continuous current through V _{CC} or GND	±100 mA
Package thermal impedance, θ _{JA} (see Note 2)	47°C/W
Storage temperature range, T _{stq}	65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions (see Note 3)

			MIN	MAX	UNIT	
Vcc	Supply voltage		0.8	2.7	V	
		V _{CC} = 0.8 V	Vcc			
V_{IH}	High-level input voltage	$V_{CC} = 1.1 \text{ V to } 1.95 \text{ V}$	0.65 × V _{CC}		V	
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7			
		V _{CC} = 0.8 V		0		
V_{IL}	Low-level input voltage	$V_{CC} = 1.1 \text{ V to } 1.95 \text{ V}$		0.35 × V _{CC}	V	
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0.7		
٧ _I	Input voltage	-	0	3.6	V	
٧o	Output voltage		0	3.6	V	
		V _{CC} = 0.8 V		0.7		
		V _{CC} = 1.1 V		3		
IOL	Low-level output current	V _{CC} = 1.4 V		5	mA	
		V _{CC} = 1.65 V		8		
		V _{CC} = 2.3 V		9		
Δt/Δν	Input transition rise or fall rate	•		20	ns/V	
T _A	Operating free-air temperature		-40	85	°C	

NOTE 3: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



NOTES: 1. The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

^{2.} The package thermal impedance is calculated in accordance with JESD 51-5.

SN74AUC06 HEX INVERTER BUFFER/DRIVER WITH OPEN-DRAIN OUTPUTS SCES471 - AUGUST 2003

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	VCC	MIN	TYP [†]	MAX	UNIT	
		I _{OL} = 100 μA	0.8 V to 2.7 V			0.2		
		$I_{OL} = 0.7 \text{ mA}$	0.8 V		0.25			
\ _{\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\}		$I_{OL} = 3 \text{ mA}$	1.1 V			0.3	V	
VOL		$I_{OL} = 5 \text{ mA}$	1.4 V			0.4	v	
		$I_{OL} = 8 \text{ mA}$	1.65 V			0.45		
		$I_{OL} = 9 \text{ mA}$	2.3 V			0.6		
II	A inputs	$V_I = V_{CC}$ or GND	0 to 2.7 V			±5	μΑ	
loff		V_I or $V_O = 2.7 V$	0			±10	μΑ	
Icc		$V_I = V_{CC}$ or GND, $I_O = 0$	0.8 V to 2.7 V			10	μΑ	
Ci	•	V _I = V _{CC} or GND	2.5 V		2.5		pF	

[†] All typical values are at $T_A = 25$ °C.

switching characteristics over recommended operating free-air temperature range, C_L = 15 pF (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	FROM (INPUT)		$V_{CC} = 0.8 \text{ V}$ $V_{CC} = 1.2 \text{ V}$ $\pm 0.1 \text{ V}$		V _{CC} = 1.5 V ± 0.1 V		V _{CC} = 1.8 V ± 0.15 V		V _{CC} = 2.5 V ± 0.2 V		UNIT	
	(IIVI O1)	(001101)	TYP	MIN	MAX	MIN	MAX	MIN	TYP	MAX	MIN	MAX	
t _{pd}	А	Y	4.2	0.8	3.6	0.5	2.6	0.5	1.4	3.1	0.4	2.2	ns

switching characteristics over recommended operating free-air temperature range, C_L = 30 pF (unless otherwise noted) (see Figure 1)

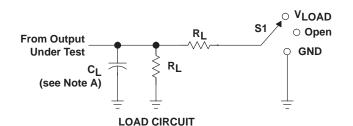
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 1.8 V ± 0.15 V			V _{CC} = 2.5 V ± 0.2 V		UNIT
	(IIVI OT)	(0011 01)	MIN	TYP	MAX	MIN	MAX	
^t pd	A	Y	0.8	1.7	2.8	0.8	1.3	ns

operating characteristics, T_A = 25°C

	PARAMETER	TEST CONDITIONS	V _{CC} = 0.8 V	V _{CC} = 1.2 V	V _{CC} = 1.5 V	V _{CC} = 1.8 V	V _{CC} = 2.5 V	UNIT
C _{pd}	Power dissipation capacitance	f = 10 MHz	2	2	2	3	3	pF

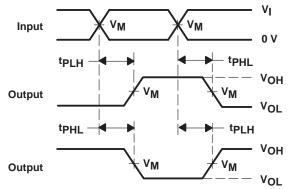
SCES471 – AUGUST 2003

PARAMETER MEASUREMENT INFORMATION (OPEN DRAIN)

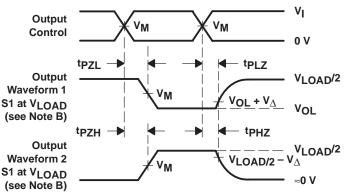


TEST	S1
t _{PZL} (see Notes E and F)	V _{LOAD}
tpLZ (see Notes E and G)	VLOAD
tPHZ/tPZH	VLOAD

	IN	IPUT	<u> </u>			_	
VCC	VI	t _r /t _f	VM	V _{LOAD}	CL	RL	$oldsymbol{V}_\Delta$
0.8 V	VCC	≤ 2 ns	V _{CC} /2	2×VCC	15 pF	2 k Ω	0.1 V
1.2 V \pm 0.1 V	VCC	≤ 2 ns	V _{CC} /2	2×VCC	15 pF	2 k Ω	0.1 V
1.5 V \pm 0.1 V	VCC	≤ 2 ns	V _{CC} /2	2×VCC	15 pF	2 k Ω	0.1 V
1.8 V \pm 0.15 V	VCC	≤ 2 ns	V _{CC} /2	2×V _{CC}	15 pF	2 k Ω	0.15 V
2.5 V \pm 0.2 V	VCC	≤ 2 ns	V _{CC} /2	2×VCC	15 pF	2 k Ω	0.15 V
1.8 V \pm 0.15 V	VCC	≤ 2 ns	V _{CC} /2	2×VCC	30 pF	1 k Ω	0.15 V
2.5 V \pm 0.2 V	VCC	≤ 2 ns	V _{CC} /2	2×VCC	30 pF	500 Ω	0.15 V







VOLTAGE WAVEFORMS ENABLE AND DISABLE TIMES LOW- AND HIGH-LEVEL ENABLING

- NOTES: A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \ \Omega$.
 - D. The outputs are measured one at a time with one transition per measurement.
 - E. Since this device has open-drain outputs, t_{PLZ} and t_{PZL} are the same as t_{pd} .
 - F. t_{PZL} is measured at V_{M} .
 - G. t_{PLZ} is measured at $V_{OL} + V_{\Delta}$.
 - H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms





PACKAGE OPTION ADDENDUM

30-Mar-2005

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins Pa	ackage Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
SN74AUC06RGYR	ACTIVE	QFN	RGY	14	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1YEAR

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

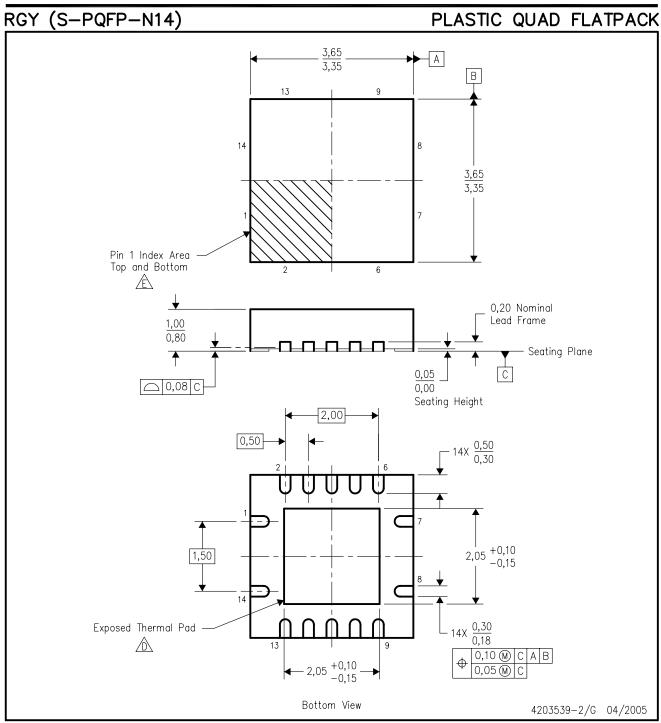
Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. QFN (Quad Flatpack No-Lead) package configuration.
- The package thermal pad must be soldered to the board for thermal and mechanical performance.
- Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated. The Pin 1 identifiers are either a molded, marked, or metal feature.
- F. Package complies to JEDEC MO-241 variation BA.



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